MPSW05, MPSW06

One Watt Amplifier Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector - Emitter Voltage	MPSW05 MPSW06	V _{CEO}	60 80	Vdc
Collector - Base Voltage	MPSW05 MPSW06	V _{CBO}	60 80	Vdc
Emitter - Base Voltage	V _{EBO}	4.0	Vdc	
Collector Current - Continuous	I _C	500	mAdc	
Total Device Dissipation @ T _A : Derate above 25°C	P _D	1.0 8.0	W mW/°C	
Total Device Dissipation @ T _C Derate above 25°C	P_D	2.5 20	W mW/°C	
Operating and Storage Junction Temperature Range	n	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

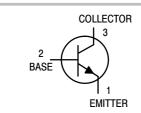
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

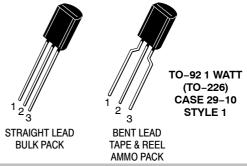
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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MARKING DIAGRAM



= 5 or 6

A = Assembly Location

Y = Year WW = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSW05G	TO-92 (Pb-Free)	5000 Units/Bulk
MPSW06G	TO-92 (Pb-Free)	5000 Units/Bulk
MPSW06RLRA	TO-92	2000/Tape & Reel
MPSW06RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPSW05, MPSW06

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•		
Collector – Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mAdc, I _B = 0)	MPSW05 MPSW06	V _(BR) CEO	60 80	_ _	Vdc
Emitter – Base Breakdown Voltage ($I_E = 100 \mu Adc, I_C = 0$)		V _{(BR)EBO}	4.0	-	Vdc
Collector Cutoff Current $(V_{CE} = 40 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 60 \text{ Vdc}, I_B = 0)$	MPSW05 MPSW06	I _{CES}	- -	0.5 0.5	μAdc
Collector Cutoff Current $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$	MPSW05 MPSW06	I _{CBO}	- -	0.1 0.1	μAdc
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)		I _{EBO}	-	0.1	μAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I_C = 50 mAdc, V_{CE} = 1.0 Vdc) (I_C = 250 mAdc, V_{CE} = 1.0 Vdc)		h _{FE}	80 60	- -	-
Collector – Emitter Saturation Voltage (I _C = 250 mAdc, I _B = 10 mAdc)		V _{CE(sat)}	-	0.4	Vdc
Base–Emitter Saturation Voltage ($I_C = 250 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)		V _{BE(sat)}	-	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I _C = 200 mAdc, V _{CE} = 5.0 Vdc, f = 20 MHz)		f _T	50	_	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)		C _{obo}	-	12	pF

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

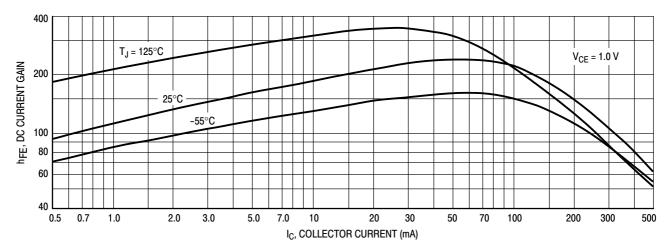


Figure 1. DC Current Gain

MPSW05, MPSW06

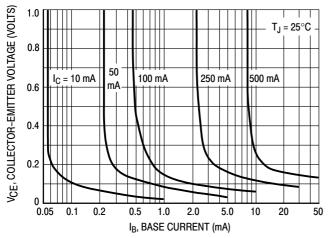


Figure 2. Collector Saturation Region

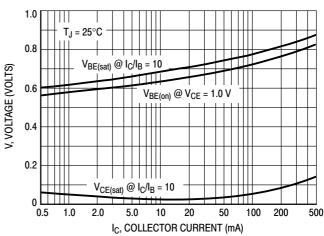


Figure 3. "On" Voltages

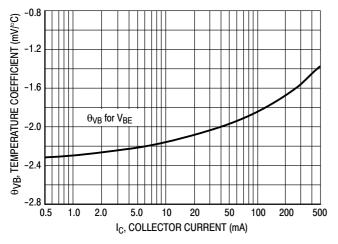


Figure 4. Base-Emitter Temperature Coefficient

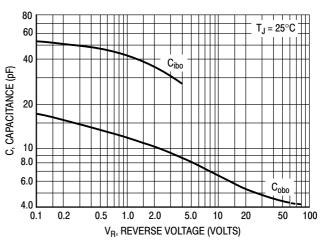


Figure 5. Capacitance

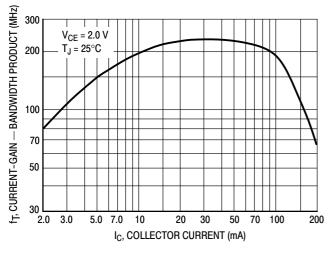


Figure 6. Current-Gain - Bandwidth Product

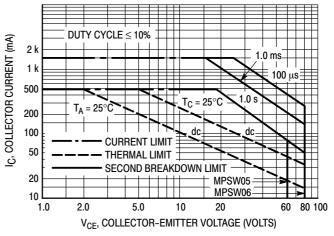
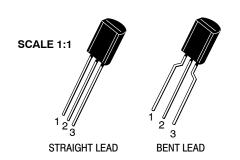


Figure 7. Active Region - Safe Operating Area

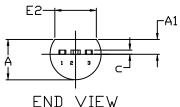


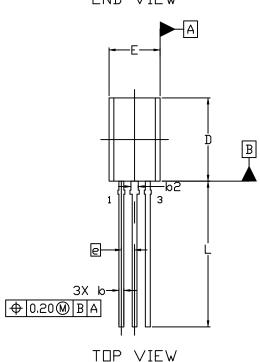


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DATE 05 MAR 2021

STRAIGHT LEAD





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
- 4. DIMENSION 6 AND 62 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION 62 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

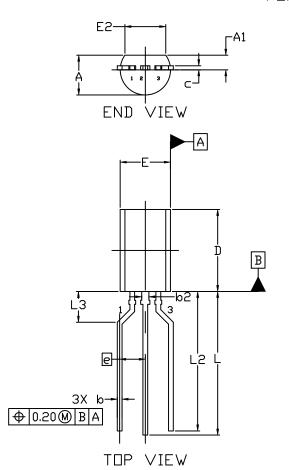
	MILLIMETERS							
DIM	MIN.	N□M.	MAX.					
Α	3.75	3.90	4.05					
A1	1.28	1.43	1.58					
b	0.38	0.465	0.55					
b2	0.62	0.70	0.78					
c	0.35	0.40	0.45					
D	7.85	8.00	8.15					
E	4.75	4.90	5.05					
E2	3.90							
е	1.27 BSC							
L	13.80 14.00 14.20							

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FORMED LEAD



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E2	3.90						
e		2.50 BSC					
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L2	13.20	13.60	14.00				
L3	3.00 REF						

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CASE 29-10 ISSUE D

DATE 05 MAR 2021

2.	EMITTER BASE COLLECTOR		BASE EMITTER COLLECTOR		ANODE ANODE CATHODE		CATHODE CATHODE ANODE		DRAIN SOURCE GATE
	GATE	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN	STYLE 8: PIN 1. 2. 3.	DRAIN GATE	2.	BASE 1	2.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE	PIN 1. 2.	MAIN TERMINAL 1	PIN 1. 2.	ANODE 1 GATE	2.	EMITTER	2.	ANODE 1 CATHODE ANODE 2
2.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER		ANODE CATHODE NOT CONNECTED		GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
2.		2.	SOURCE GATE DRAIN		GATE SOURCE DRAIN	PIN 1. 2.	EMITTER	2.	MT 1
	V _{CC}			PIN 1. 2.		PIN 1. 2.	NOT CONNECTED ANODE CATHODE		
	GATE	STYLE 32: PIN 1. 2. 3.	BASE COLLECTOR EMITTER	2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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